

BAS16T, BAW56T, BAV70T, BAV99T

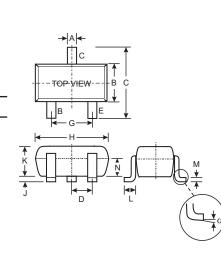
SURFACE MOUNT FAST SWITCHING DIODE

Features

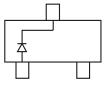
- Ultra-Small Surface Mount Package
- Fast Switching Speed
- For General Purpose Switching Applications
- High Conductance
- Lead Free/RoHS Compliant (Note 1)

Mechanical Data

- Case: SOT-523, Molded Plastic
- Case material UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish).
- Polarity: See Diagrams Below
- Marking: See Diagrams Below & Page 3
- Ordering Information, see Page 2
- Weight: 0.002 grams (approximate)



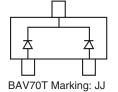
SOT-523									
Dim	Min	Мах	Тур						
Α	0.15	0.30	0.22						
В	0.75	0.85	0.80						
С	1.45	1.75	1.60						
D		_	0.50						
G	0.90	1.10	1.00						
Н	1.50	1.70	1.60						
J	0.00	0.10	0.05						
К	0.60	0.80	0.75						
L	0.10	0.30	0.22						
М	0.10	0.20	0.12						
Ν	0.45	0.65	0.50						
α	0°	8°	—						
All Dimensions in mm									





BAS16T Marking: A2

BAW56T Marking: JD





BAV99T Marking: JE

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit		
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} VR	85	V		
RMS Reverse Voltage	V _{R(RMS)}	60	V		
Forward Continuous Current (Note 2) Single diode Double diode	I _{FM}	155 75	mA		
Repetitive Peak Forward Current	I _{FRM}	500	mA		
Non-Repetitive Peak Forward Surge Current $@ t = 1.0 \mu s$ @ t = 1.0ms @ t = 1.0s	I _{FSM}	4.0 1.0 0.5	A		
Power Dissipation (Note 2)	Pd	150	mW		
Thermal Resistance Junction to Ambient (Note 2)	R _{0JA}	833	°C/W		
Operating and Storage Temperature Range	T_{j} , T_{STG}	-65 to +150	°C		

Notes: 1. No purposefully added lead.

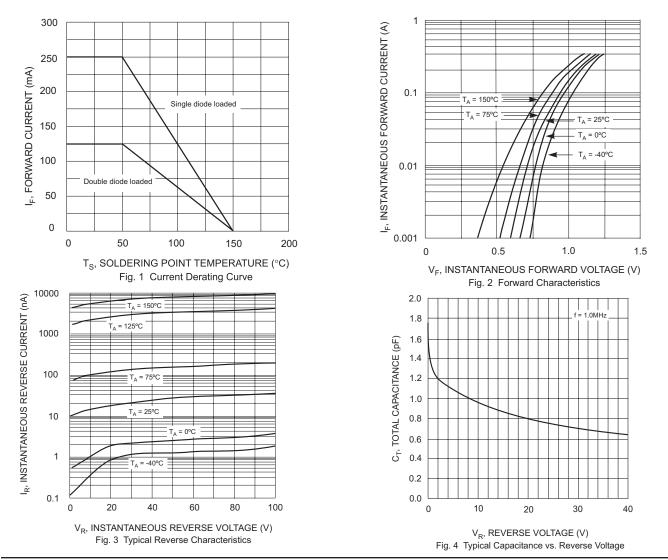
2. Device mounted on FR-4 PC board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Electrical Characteristics @ T _A = 25°C unless otherwise specified									
Characteristic S		Min	Тур	Мах	Unit	Test Condition			
Reverse Breakdown Voltage (Note 3)	V _{(BR)R}	85	—	—	V	I _R = 100μA			
Forward Voltage	VF	_	_	0.715 0.855 1.0 1.25	V	$ \begin{array}{l} I_F = 1.0mA \\ I_F = 10mA \\ I_F = 50mA \\ I_F = 150mA \end{array} $			
Leakage Current (Note 3)	I _R			2.0 100 60 30	μΑ μΑ μΑ nA	$ \begin{array}{l} V_{R} = 75V \\ V_{R} = 75V, \ T_{j} = 150^{\circ}C \\ V_{R} = 25V, \ T_{j} = 150^{\circ}C \\ V_{R} = 25V \end{array} $			
Total Capacitance	Ст		1.5		pF	V _R = 0, f = 1.0MHz			
Reverse Recovery Time	t _{rr}			4.0	ns	$\label{eq:lf} \begin{array}{l} I_F = I_R = 10 m A, \\ I_{rr} = 0.1 \ x \ I_R, \ R_L = 100 \Omega \end{array}$			

Notes: 3. Short duration test pulse to minimize self-heating effect.

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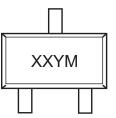


Ordering Information (Note 4)

Device	Packaging	Shipping		
BAS16T-7-F	SOT-523	3000/Tape & Reel		
BAW56T-7-F	SOT-523	3000/Tape & Reel		
BAV70T-7-F	SOT-523	3000/Tape & Reel		
BAV99T-7-F	SOT-523	3000/Tape & Reel		

4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf. Notes:





 $\begin{array}{l} XX = \mbox{Product Type Marking Code (See Page 1, e.g. A2 = BAS16T)} \\ YM = \mbox{Date Code Marking} \\ Y = \mbox{Year (ex: N = 2002)} \\ M = \mbox{Month (ex: 9 = September)} \end{array}$

Date Code Key

Year	2002	2003	200	4 20	005	2006	2007	2008	2009	20	10	2011	2012
Code	N	Р	R		S	Т	U	V	W)	x	Y	Z
Mont	h	Jan	Feb	March	Apr	Ma	/ Ju	n Jul	Aug	Sep	Oct	Nov	Dec
Code	e	1	2	3	4	5	6	7	8	9	0	Ν	D

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